Highlights

Modeling the Impact of Iron Defect Variability on Silicon Solar Cell Performance Across Different Scenarios

Oleg Olikh,Oleksii Zavhorodnii

- The iron defect transformation effect on Si solar cells' performance was studied using SCAPS simulation
- Short-circuit current changes are most suitable for estimating iron impurity concentration.
- Open-circuit voltage changes are a non-monotonic function of iron concentration at low doping levels.
- Monochromatic illumination is more effective than AM1.5 for accurate iron concentration estimation.